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#### **NPN MEDIUM POWER TRANSISTORS IN SOT223**

#### **Features**

- BV<sub>CEO</sub> > 45V, 60V & 80V
- $I_C = 1A$  High Continuous Collector Current
- I<sub>CM</sub> = 2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V<sub>CE(sat)</sub> < 500mV @ 0.5A</li>
- Gain Groups 10 and 16
- Complementary PNP Types: BCP51, 52 and 53
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

#### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
  Solderable per MIL-STD-202, Method 208
- Weight: 0.112 grams (Approximate) (63)

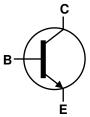
#### **Applications**

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

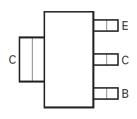
SOT223







Device Symbol



Top View Pin-Out

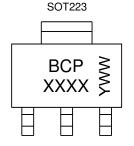
#### Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel	
BCP54TA	AEC-Q101	BCP 54	7	12	1,000	
BCP5410TA	AEC-Q101	BCP 5410	7	12	1,000	
BCP5416TA	AEC-Q101	BCP 5416	7	12	1,000	
BCP5416QTA	Automotive	BCP 5416	7	12	1,000	
BCP55TA	AEC-Q101	BCP 55	7	12	1,000	
BCP5510TA	AEC-Q101	BCP 5510	7	12	1,000	
BCP5516TA	AEC-Q101	BCP 5516	7	12	1,000	
BCP56TA	AEC-Q101	BCP 56	7	12	1,000	
BCP5610TA	AEC-Q101	BCP 5610	7	12	1,000	
BCP5616TA	AEC-Q101	BCP 5616	7	12	1,000	
BCP5616TC	AEC-Q101	BCP 5616	13	12	4,000	
BCP5616QTA	Automotive	Refer to http://diodes.com/datasheets/BCP5616Q.pdf				
BCP5616QTC	Automotive	Refer to http://diodes.com/datasheets/BCP5616Q.pdf				

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**



BCP = Product Type Marking Code, Line 1 XXXX = Product Type Marking Code, Line 2 as follows:

BCP54 = 54 BCP55 = 55 BCP56 = 56 BCP5410 = 5410 BCP5510 = 5510 BCP5610 = 5610 BCP5416 = 5416 BCP5516 = 5516 BCP5616 = 5616

YWW = Date Code Marking

Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCP54	BCP55	BCP56	Unit	
Collector-Base Voltage	V <sub>CBO</sub>	45	60	100	V	
Collector-Emitter Voltage	V <sub>CEO</sub>	45	60	80	V	
Emitter-Base Voltage	V <sub>EBO</sub>		5			
Continuous Collector Current	Ic		1			
Peak Pulse Collector Current	I <sub>CM</sub>		2			
Continuous Base Current	IB		100			
Peak Pulse Base Current	I <sub>BM</sub>	200			- mA	

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	$P_{D}$	2	W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	62	°C/W
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	19.4	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C	

# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	٧	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

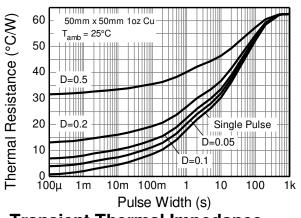
<sup>6.</sup> For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

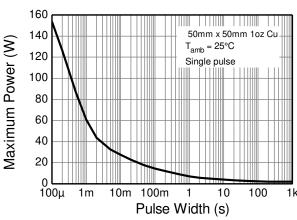
<sup>7.</sup> Thermal resistance from junction to solder-point (at the end of the collector lead).

<sup>8.</sup> Refer to JEDEC specification JESD22-A114 and JESD22-A115.



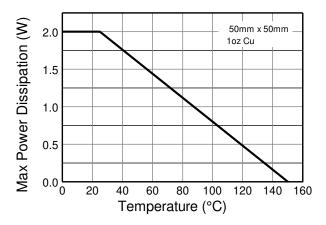
## **Thermal Characteristics and Derating Information**





# **Transient Thermal Impedance**

**Pulse Power Dissipation** 



**Derating Curve** 

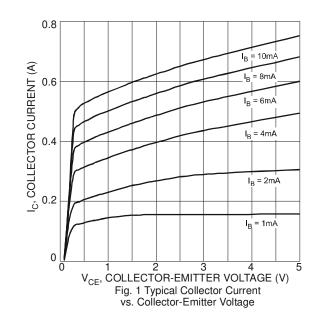


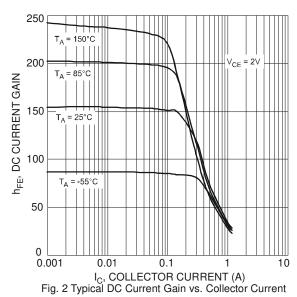
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCP54 BCP55 BCP56	BV <sub>CBO</sub>	45 60 100	-	-	٧	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BCP54 BCP55 BCP56	BV <sub>CEO</sub>	45 60 80	-	-	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	5	-	-	V	I <sub>E</sub> = 10μA
Collector Cut-Off Current		I <sub>CBO</sub>	-	-	0.1 20	μА	V <sub>CB</sub> = 30V V <sub>CB</sub> = 30V, T <sub>A</sub> = +150°C
Emitter Cut-Off Current		I <sub>EBO</sub>	-	-	20	nA	V <sub>EB</sub> = 4V
Static Forward Current Transfer Ratio (Note 9)	All versions	h <sub>FE</sub>	25 40 25	- - -	- 250 -	_	$I_C = 5mA$ , $V_{CE} = 2V$ $I_C = 150mA$ , $V_{CE} = 2V$ $I_C = 500mA$ , $V_{CE} = 2V$
Static Forward Surrent Transfer Hatio (Note 3)	10 gain grp	1 I'IFE	63	-	160		$I_C = 150 \text{mA}, V_{CE} = 2V$
	16 gain grp		100	-	250		$I_C = 150 \text{mA}, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 9)		V <sub>CE(sat)</sub>	-	-	0.5	V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
Base-Emitter Turn-On Voltage (Note 9)		V <sub>BE(on)</sub>	-	-	1.0	V	$I_C = 500 \text{mA}, V_{CE} = 2V$
Transition Frequency		f⊤	150	-	-	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V}$ f = 100MHz
Output Capacitance		Cobo	-	-	25	pF	$V_{CB} = 10V$ , $f = 1MHz$

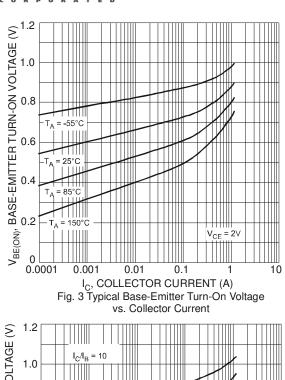
Note:

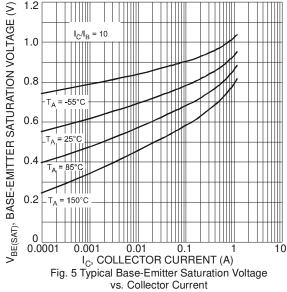
9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

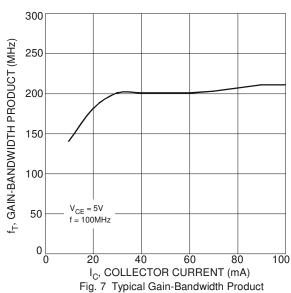












vs. Collector Current

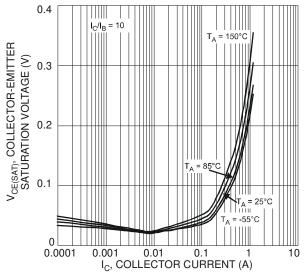


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

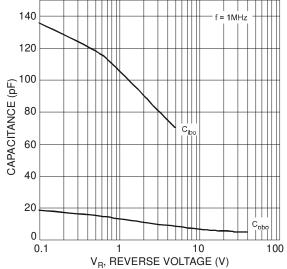
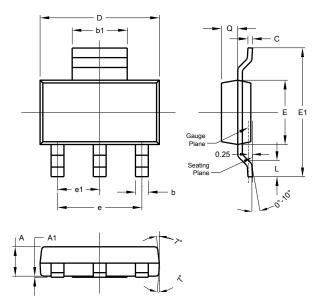


Fig. 6 Typical Capacitance Characteristics



## **Package Outline Dimensions**

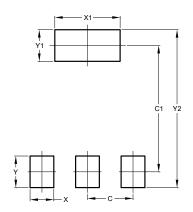
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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